

Real-Time Clock (RTC) With NVRAM Control

Features

- ➤ Direct clock/calendar replacement for IBM[®] AT-compatible computers and other applications
- ➤ Functionally compatible with the DS1285
 - Closely matches MC146818A pin configuration
- ➤ 114 bytes of general nonvolatile storage
- ➤ Automatic backup and writeprotect control to external SRAM
- ➤ 160 ns cycle time allows fast bus operation
- ➤ Less than 0.5 μA load under battery operation
- ➤ 14 bytes for clock/calendar and control

- ➤ Calendar in day of the week, day of the month, months, and years, with automatic leap-year adjustment
- ➤ Time of day in seconds, minutes, and hours
 - 12- or 24-hour format
 - Optional daylight saving adjustment
- ➤ BCD or binary format for clock and calendar data
- ➤ Programmable square wave output
- ➤ Three individually maskable interrupt event flags:
 - Periodic rates from $122\,\mu s$ to 500~ms
 - Time-of-day alarm once per second to once per day
 - End-of-clock update cycle
- ➤ 24-pin plastic DIP or SOIC

General Description

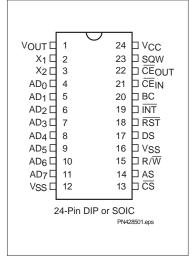
The CMOS bq4285 is a low-power microprocessor peripheral providing a time-of-day clock and 100-year calendar with alarm features and battery operation. Other features include three maskable interrupt sources, square wave output, and 114 bytes of general nonvolatile storage.

The bq4285 write-protects the clock, calendar, and storage registers during power failure. A backup battery then maintains data and operates the clock and calendar.

The bq4285 is a fully compatible realtime clock for IBM AT-compatible computers and other applications. The only external components are a 32.768kHz crystal and a backup battery.

The bq4285 integrates a battery-backup controller to make a standard CMOS SRAM nonvolatile during power-fail conditions. During power-fail, the bq4285 automatically write-protects the external SRAM and provides a $V_{\rm CC}$ output sourced from the clock backup battery.

Pin Connections

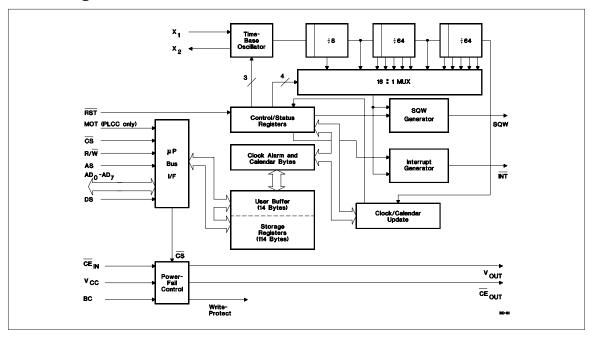




Pin Names

| AD ₀ –AD ₇ | Multiplexed address/data input/output |
|-------------------------------------|---------------------------------------|
| MOT | Bus type select input |
| CS | Chip select input |
| AS | Address strobe input |
| DS_ | Data strobe input |
| R/W | Read/write input |
| $\overline{\text{INT}}$ | Interrupt request output |
| RST | Reset input |
| SQW | Square wave output |
| BC | 3V backup cell input |
| X1-X2 | Crystal inputs |
| NC | No connect |
| $\overline{\text{CE}}_{\text{IN}}$ | RAM chip enable input |
| $\overline{\text{CE}}_{\text{OUT}}$ | RAM chip enable output |
| V_{OUT} | Supply output |
| V_{CC} | +5V supply |
| V_{SS} | Ground |

Block Diagram



Pin Descriptions

$\begin{array}{ll} AD_0\text{--}AD_7 & Multiplexed \ address/data \ input/output \end{array}$

The bq4285 bus cycle consists of two phases: the address phase and the data-transfer phase. The address phase precedes the data-transfer phase. During the address phase, an address placed on AD_0 – AD_7 is latched into the bq4285 on the falling edge of the AS signal. During the data-transfer phase of the bus cycle, the AD_0 – AD_7 pins serve as a bidirectional data bus.

MOT Connect to VSS for correct operation

CS Chip select input

 $\overline{\text{CS}}$ should be driven low and held stable during the data-transfer phase of a bus cycle accessing the bq4285.

Table 1. Bus Setup

| Bus Type | MOT Level | DS Equivalent | R/W Equivalent | AS Equivalent |
|-------------|--------------|--|---|------------------|
| | | | _ | |
| Intel | $V_{\rm SS}$ | $\frac{\overline{RD},}{\overline{MEMR},}$ or $\overline{I/OR}$ | $\overline{\overline{WR}}, \\ \overline{MEMW}, \\ or \overline{I/OW}$ | ALE |

power-

AS Address strobe input

AS serves to demultiplex the address/data bus. The falling edge of AS latches the address on AD_0 – AD_7 . This demultiplexing process is independent of the \overline{CS} signal.

tain their states through down/power-up cycles.

Square-wave output

SQW may output a programmable frequency square-wave signal during normal ($V_{\rm CC}$ valid) system operation. Any one of the 13 specific frequencies may be selected

the 13 specific frequencies may be selected through register A. This pin is held low when the square-wave enable bit (SQWE) in register B is 0 (see the Control/Status

Reset may be disabled by connecting \overline{RST} to V_{CC} . This allows the control bits to re-

 $Registers\ section).$

SQW

DS Data strobe input

With MOT = V_{SS} , the DS input is provided a signal similar to \overline{RD} , \overline{MEMR} , or $\overline{I/OR}$ in an BC Intel-based system. The falling edge on DS is used to enable the outputs during a read cycle.

3V backup cell input

BC should be connected to a 3V backup cell for RTC operation and storage register non-volatility in the absence of power. When $V_{\rm CC}$ slews down past $V_{\rm BC}$ (3V typical), the integral control circuitry switches the power source to BC. When $V_{\rm CC}$ returns above $V_{\rm BC}$, the power source is switched to $V_{\rm CC}$.

Upon power-up, a voltage within the $V_{\rm BC}$ range must be present on the BC pin for the oscillator to start up.

R/W Read/write input

With $\underline{MOT} = \underline{V_{SS}}$, $\underline{R/W}$ is provided a signal similar to \overline{WR} , \underline{MEMW} , or $\overline{I/OW}$ in an Intelbased system. The rising edge on $\overline{R/W}$ latches data into the bq4285.

X1-X2 Crystal inputs

The X1–X2 inputs are provided for an external 32.768Khz quartz crystal, Daiwa DT-26 or equivalent, with 6pF load capacitance. A trimming capacitor may be necessary for extremely precise time-base generation.

INT Interrupt request output

 $\overline{\rm INT}$ is an open-drain output. $\overline{\rm INT}$ is asserted low when any event flag is set and the corresponding event enable bit is also set. $\overline{\rm INT}$ becomes high-impedance whenever register C is read (see the Control/Status Registers section).

$\overline{\text{CE}}_{\text{IN}}$ External RAM chip enable input, active low

 \overline{CE}_{IN} should be driven low to enable the controlled external RAM. \overline{CE}_{IN} is internally pulled up with a $50K\Omega$ resistor.

RST Reset input

The bq4285 is reset when \overline{RST} is pulled low. When reset, \overline{INT} becomes high-impedance, and the bq4285 is not accessible. Table 4 in the Control/Status Registers section lists the register bits that are cleared by a reset.

CE_{OUT} External RAM chip enable output, active low

When power is valid, $\overline{\text{CE}}_{\text{OUT}}$ reflects $\overline{\text{CE}}_{\text{IN}}$.

V_{OUT} Supply output

 $V_{\rm OUT}$ provides the higher of $V_{\rm CC}$ or $V_{\rm BC}$, switched internally, to supply external RAM.

V_{CC} +5V supply

Vss Ground

Functional Description Address Map

The bq4285 provides 14 bytes of clock and control/status registers and 114 bytes of general nonvolatile storage. Figure 1 illustrates the address map for the bq4285.

Update Period

The update period for the bq4285 is one second. The bq4285 updates the contents of the clock and calendar locations during the update cycle at the end of each up-

date period (see Figure 2). The alarm flag bit may also be set during the update cycle.

The bq4285 copies the local register updates into the user buffer accessed by the host processor. When a 1 is written to the update transfer inhibit bit (UTI) in register B, the user copy of the clock and calendar bytes remains unchanged, while the local copy of the same bytes continues to be updated every second.

The update-in-progress bit (UIP) in register A is set t_{BUC} time before the beginning of an update cycle (see Figure 2). This bit is cleared and the update-complete flag (UF) is set at the end of the update cycle.

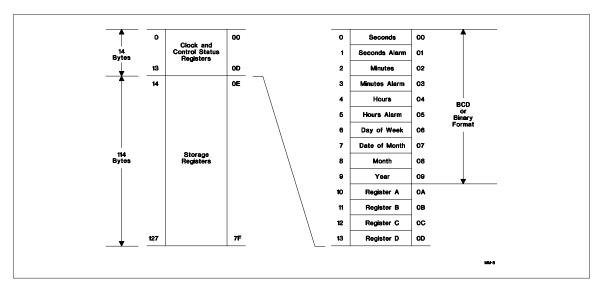


Figure 1. Address Map

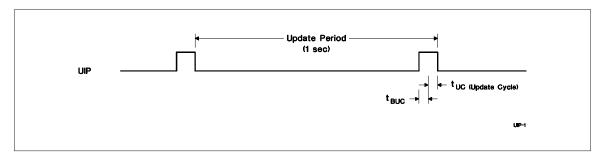


Figure 2. Update Period Timing and UIP

Programming the RTC

The time-of-day, alarm, and calendar bytes can be written in either the BCD or binary format (see Table 2).

These steps may be followed to program the time, alarm, and calendar:

- 1. Modify the contents of register B:
 - a. Write a 1 to the UTI bit to prevent transfers between RTC bytes and user buffer.
 - Write the appropriate value to the data format (DF) bit to select BCD or binary format for all time, alarm, and calendar bytes.

- c. Write the appropriate value to the hour format (HF) bit.
- 2. Write new values to all the time, alarm, and calendar locations.
- 3. Clear the UTI bit to allow update transfers.

On the next update cycle, the RTC updates all 10 bytes in the selected format.

Table 2. Time, Alarm, and Calendar Formats

| | | | Range | |
|---------|-----------------------------|---------|---------------------------|---------------------------|
| Address | RTC Bytes | Decimal | Binary | Binary-Coded Decimal |
| 0 | Seconds | 0–59 | 00H-3BH | 00H–59H |
| 1 | Seconds alarm | 0–59 | 00H-3BH | 00H–59H |
| 2 | Minutes | 0–59 | 00H-3BH | 00H–59H |
| 3 | Minutes alarm | 0–59 | 00H-3BH | 00H-59H |
| 4 | Hours, 12-hour format | 1–12 | 01H–OCH AM; 81H–8CH PM | 01H–12H AM; 81H–92H PM |
| | Hours, 24-hour format | 0–23 | 00H-17H | 00H-23H |
| 5 | Hours alarm, 12-hour format | 1–12 | 01H–OCH AM; 81H–8CH PM | 01H–12H AM; 81H–92H PM |
| | Hours alarm, 24-hour format | 0–23 | 00H-17H | 00H-23H |
| 6 | Day of week (1=Sunday) | 1–7 | 01H-07H | 01H-07H |
| 7 | Day of month | 1–31 | 01H-1FH | 01H-31H |
| 8 | Month | 1–12 | 01H-0CH | 01H-12H |
| 9 | Year | 0–99 | 00H-63H | 00H-99H |

Square-Wave Output

The bq4285 divides the 32.768kHz oscillator frequency to produce the 1 Hz update frequency for the clock and calendar. Thirteen taps from the frequency divider are fed to a 16:1 multiplexer circuit. The output of this mux is fed to the SQW output and periodic interrupt generation circuitry. The four least-significant bits of register A, RS0–RS3, select among the 13 taps (see Table 3). The square-wave output is enabled by writing a 1 to the square-wave enable bit (SQWE) in register B.

Interrupts

The bq4285 allows three individually selected interrupt events to generate an interrupt request. These three interrupt events are:

- The periodic interrupt, programmable to occur once every 122 µs to 500 ms
- The alarm interrupt, programmable to occur once per second to once per day

■ The update-ended interrupt, which occurs at the end of each update cycle

Each of the three interrupt events is enabled by an individual interrupt-enable bit in register B. When an event occurs, its event flag bit in register C is set. If the corresponding event enable bit is also set, then an interrupt request is generated. The interrupt request flag bit (INTF) of register C is set with every interrupt request. Reading register C clears all flag bits, including INTF, and makes INT high-impedance.

Two methods can be used to process bq4285 interrupt events:

- Enable interrupt events and use the interrupt request output to invoke an interrupt service routine.
- Do not enable the interrupts and use a polling routine to periodically check the status of the flag bits.

The individual interrupt sources are described in detail in the following sections.

| Table 3. Square-Wave Frequency/Periodic Interrupt Rate |
|--|
| |

| | Registe | er A Bits | | Square | Wave | Periodic | Interrupt |
|-----|---------|-----------|-----|-----------|-------|----------|-----------|
| RS3 | RS2 | RS1 | RS0 | Frequency | Units | Period | Units |
| 0 | 0 | 0 | 0 | None | | None | |
| 0 | 0 | 0 | 1 | 256 | Hz | 3.90625 | ms |
| 0 | 0 | 1 | 0 | 128 | Hz | 7.8125 | ms |
| 0 | 0 | 1 | 1 | 8.192 | kHz | 122.070 | μs |
| 0 | 1 | 0 | 0 | 4.096 | kHz | 244.141 | μs |
| 0 | 1 | 0 | 1 | 2.048 | kHz | 488.281 | μs |
| 0 | 1 | 1 | 0 | 1.024 | kHz | 976.5625 | μs |
| 0 | 1 | 1 | 1 | 512 | Hz | 1.95315 | ms |
| 1 | 0 | 0 | 0 | 256 | Hz | 3.90625 | ms |
| 1 | 0 | 0 | 1 | 128 | Hz | 7.8125 | ms |
| 1 | 0 | 1 | 0 | 64 | Hz | 15.625 | ms |
| 1 | 0 | 1 | 1 | 32 | Hz | 31.25 | ms |
| 1 | 1 | 0 | 0 | 16 | Hz | 62.5 | ms |
| 1 | 1 | 0 | 1 | 8 | Hz | 125 | ms |
| 1 | 1 | 1 | 0 | 4 | Hz | 250 | ms |
| 1 | 1 | 1 | 1 | 2 | Hz | 500 | ms |

Periodic Interrupt

The mux output used to drive the SQW output also drives the interrupt-generation circuitry. If the periodic interrupt event is enabled by writing a 1 to the periodic interrupt enable bit (PIE) in register C, an interrupt request is generated once every 122µs to 500ms. The period between interrupts is selected by the same bits in register A that select the square wave frequency (see Table 3).

Alarm Interrupt

During each update cycle, the RTC compares the hours, minutes, and seconds bytes with the three corresponding alarm bytes. If a match of all bytes is found, the alarm interrupt event flag bit, AF in register C, is set to 1. If the alarm event is enabled, an interrupt request is generated.

An alarm byte may be removed from the comparison by setting it to a "don't care" state. An alarm byte is set to a "don't care" state by writing a 1 to each of its two most-significant bits. A "don't care" state may be used to select the frequency of alarm interrupt events as follows:

- If none of the three alarm bytes is "don't care," the frequency is once per day, when hours, minutes, and seconds match.
- If only the hour alarm byte is "don't care," the frequency is once per hour, when minutes and seconds match.
- If only the hour and minute alarm bytes are "don't care," the frequency is once per minute, when seconds match.
- If the hour, minute, and second alarm bytes are "don't care," the frequency is once per second.

Update Cycle Interrupt

The update cycle ended flag bit (UF) in register C is set to a 1 at the end of an update cycle. If the update interrupt enable bit (UIE) of register B is 1, and the update transfer inhibit bit (UTI) in register B is 0, then an interrupt request is generated at the end of each update cycle

Accessing RTC bytes

Time and calendar bytes read during an update cycle may be in error. Three methods to access the time and calendar bytes without ambiguity are:

- Enable the update interrupt event to generate interrupt requests at the end of the update cycle. The interrupt handler has a maximum of 999ms to access the clock bytes before the next update cycle begins (see Figure 3).
- Poll the update-in-progress bit (UIP) in register A. If UIP = 0, the polling routine has a minimum of t_{BUC} time to access the clock bytes (see Figure 3).
- Use the periodic interrupt event to generate interrupt requests every tpl time, such that UIP = 1 always occurs between the periodic interrupts. The interrupt handler will have a minimum of tpl/2 + tbuc time to access the clock bytes (see Figure 3).

Oscillator Control

When power is first applied to the bq4285 and $V_{\rm CC}$ is above $V_{\rm PFD}$, the internal oscillator and frequency divider are turned on by writing a 010 pattern to bits 4 through 6 of register A. A pattern of 11X turns the oscillator on but keeps the frequency divider disabled. Any other pattern to these bits keeps the oscillator off.

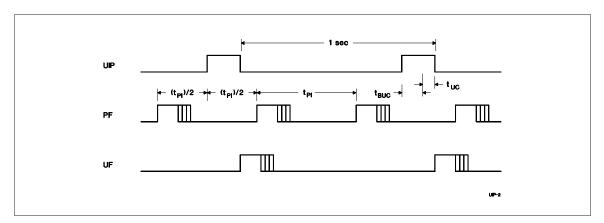


Figure 3. Update-Ended/Periodic Interrupt Relationship

Power-Down/Power-Up Cycle

The bq4285 continuously monitors $V_{\rm CC}$ for out-of-tolerance. During a power failure, when $V_{\rm CC}$ falls below $V_{\rm PFD}$ (4.17V typical), the bq4285 write-protects the clock and storage registers. When $V_{\rm CC}$ is below $V_{\rm BC}$ (3V typical), the power source is switched to BC. RTC operation and storage data are sustained by a valid backup energy source. When $V_{\rm CC}$ is above $V_{\rm BC}$, the power source is $V_{\rm CC}$. Write-protection continues for $t_{\rm CSR}$ time after $V_{\rm CC}$ rises above $V_{\rm PFD}$.

An external CMOS static RAM is battery-backed using the V_{OUT} and chip enable output pins from the bq4285. As the voltage input V_{CC} slows down during a power failure, the chip enable output, $\overline{CE}_{O\underline{UT}}$ is forced inactive independent of the chip enable input \overline{CE}_{IN}

This activity unconditionally write-protects the external SRAM as $V_{\rm CC}$ falls below $V_{\rm PFD}.$ If a memory access is in process to the external SRAM during power-fail detection, that memory cycle continues to completion before the memory is write-protected. If the memory cycle is not terminated within time $t_{\rm WPT}$ (30µs maximum), the chip enable output is unconditionally driven high, write-protecting the controlled SRAM.

As the supply continues to fall past V_{PFD} , an internal switching device forces V_{OUT} to the external backup energy source. \overline{CE}_{OUT} is held high by the V_{OUT} energy source.

During power-up, V_{OUT} is switched back to the 5V supply as V_{CC} rises above the backup cell input voltage sourcing V_{OUT} . \overline{CE}_{OUT} is held inactive for time t_{CER} (200ms maximum) after the power supply has reached V_{PFD} , independent of the \overline{CE}_{IN} input, to allow for processor stabilization.

During power-valid operation, the $\overline{\text{CE}}_{\text{IN}}$ input is passed through to the $\overline{\text{CE}}_{\text{OUT}}$ output with a propagation delay of less than 10ns.

Figure 4 shows the hardware hookup for the external RAM.

A primary backup energy source input is provided on the bq4285. The BC input accepts a 3V primary battery, typically some type of lithium chemistry. To prevent battery drain when there is no valid data to retain, $V_{\rm OUT}$ and $\overline{\rm CE}_{\rm OUT}$ are internally isolated from BC by the initial connection of a battery. Following the first application of $V_{\rm CC}$ above $V_{\rm PFD}$, this isolation is broken, and the backup cell provides power to $V_{\rm OUT}$ and $\overline{\rm CE}_{\rm OUT}$ for the external SRAM.

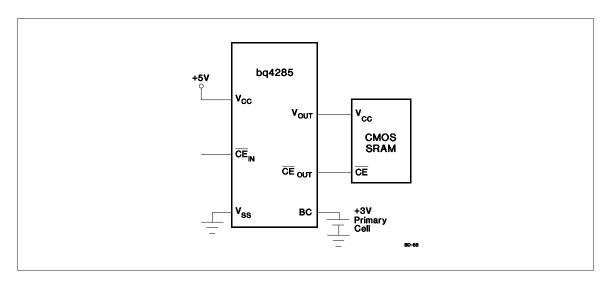


Figure 4. External RAM Hookup to the bq4285 RTC

Control/Status Registers

The four control/status registers of the bq4285 are accessible regardless of the status of the update cycle (see Table 4).

Register A

| Register A Bits | | | | | | | | |
|-----------------|-----|-----|-----|-----|-----|-----|-----|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| UIP | OS2 | OS1 | OS0 | RS3 | RS2 | RS1 | RS0 | |

Register A programs:

- The frequency of the square-wave and the periodic event rate.
- Oscillator operation.

Register A provides:

Status of the update cycle.

RS0-RS3 - Frequency Select

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|-----|-----|-----|-----|
| _ | - | _ | _ | RS3 | RS2 | RS1 | RS0 |

These bits select one of the 13 frequencies for the SQW output and the periodic interrupt rate, as shown in Table 3.

OS0-OS2 - Oscillator Control

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|-----|-----|-----|---|---|---|---|
| _ | OS2 | OS1 | OS0 | _ | _ | _ | _ |

These three bits control the state of the oscillator and divider stages. A pattern of 010 enables RTC operation by turning on the oscillator and enabling the frequency divider. A pattern of 11X turns the oscillator on, but keeps

the frequency divider disabled. When 010 is written, the RTC begins its first update after $500 \, \mathrm{ms}$.

UIP - Update Cycle Status

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| UIP | - | - | _ | - | - | - | - |

This read-only bit is set prior to the update cycle. When UIP equals 1, an RTC update cycle may be in progress. UIP is cleared at the end of each update cycle. This bit is also cleared when the update transfer inhibit (UTI) bit in register B is 1.

Register B

| Register B Bits | | | | | | | | |
|-----------------|-----|-----|-----|------|----|----|-----|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| UTI | PIE | AIE | UIE | SOWE | DF | HF | DSE | |

Register B enables:

- Update cycle transfer operation
- Square-wave output
- Interrupt events
- Daylight saving adjustment

Register B selects:

■ Clock and calendar data formats

All bits of register B are read/write.

Table 4. Control/Status Registers

| | | | | | Bit Name and State on Reset | | | | | | | | | | | | | | |
|------|---------------|------|------------------|------|-----------------------------|-----|----|-----|----|-----|----|------|----|-----|----|-----|----|-------|-----|
| Reg. | Loc. (Hex) | Read | Write | 7 (M | SB) | 6 | 5 | 5 | 5 | 4 | ı | 3 | | 2 | 2 | 1 | | 0 (LS | SB) |
| A | 0A | Yes | Yes^1 | UIP | na | OS2 | na | OS1 | na | OS0 | na | RS3 | na | RS2 | na | RS1 | na | RS0 | na |
| В | 0B | Yes | Yes | UTI | na | PIE | 0 | AIE | 0 | UIE | 0 | SQWE | 0 | DF | na | HF | na | DSE | na |
| С | 0C | Yes | No | INTF | 0 | PF | 0 | AF | 0 | UF | 0 | - | 0 | - | 0 | - | 0 | - | 0 |
| D | 0D | Yes | No | VRT | na | - | 0 | - | 0 | - | 0 | - | 0 | - | 0 | - | 0 | - | 0 |

Notes:

na = not affected.

1. Except bit 7.

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DSE - Daylight Saving Enable

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|-----|
| - | - | - | - | - | - | - | DSE |

This bit enables daylight-saving time adjustments when written to 1:

- On the last Sunday in October, the first time the bq4285 increments past 1:59:59 AM, the time falls back to 1:00:00 AM.
- On the first Sunday in April, the time springs forward from 2:00:00 AM to 3:00:00 AM.

HF - Hour Format

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|----|---|
| - | - | - | - | - | - | HF | - |

This bit selects the time-of-day and alarm hour format:

- 1 = 24-hour format
- 0 = 12-hour format

DF - Data Format

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|----|---|---|
| - | - | - | - | - | DF | - | - |

This bit selects the numeric format in which the time, alarm, and calendar bytes are represented:

- 1 = Binary
- 0 = BCD

SQWE - Square-Wave Enable

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|------|---|---|---|
| - | - | - | - | SQWE | - | - | - |

This bit enables the square-wave output:

- 1 = Enabled
- 0 = Disabled and held low

UIE - Update Cycle Interrupt Enable

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|-----|---|---|---|---|
| - | - | _ | UIE | - | _ | - | - |

This bit enables an interrupt request due to an update ended interrupt event:

- 1 = Enabled
- 0 = Disabled

The UIE bit is automatically cleared when the UTI bit equals 1.

AIE - Alarm Interrupt Enable

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|-----|---|---|---|---|---|
| _ | _ | AIE | _ | _ | _ | _ | _ |

This bit enables an interrupt request due to an alarm interrupt event:

- 1 = Enabled
- 0 = Disabled

PIE - Periodic Interrupt Enable

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|-----|---|---|---|---|---|---|
| - | PIE | - | - | - | - | - | - |

This bit enables an interrupt request due to a periodic interrupt event:

- 1 = Enabled
- 0 = Disabled

UTI - Update Transfer Inhibit

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| UTI | - | - | - | - | - | - | - |

This bit inhibits the transfer of RTC bytes to the user buffer:

- 1 = Inhibits transfer and clears UIE
- 0 = Allows transfer

Register C

| | | | Registe | r C Bits | 5 | | |
|------|----|----|---------|----------|---|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| INTF | PF | AF | UF | 0 | 0 | 0 | 0 |

Register C is the read-only event status register.

Bits 0-3 - Unused Bits

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| - | - | - | - | 0 | 0 | 0 | 0 |

These bits are always set to 0.

UF - Update-Event Flag

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|---|---|----|---|---|---|---|--|
| - | - | - | UF | - | - | - | - | |

This bit is set to a 1 at the end of the update cycle. Reading register C clears this bit.

AF - Alarm Event Flag

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|----|---|---|---|---|---|
| - | _ | AF | _ | _ | _ | _ | _ |

This bit is set to a 1 when an alarm event occurs. Reading register C clears this bit.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|----|---|---|---|---|---|---|
| - | PF | - | - | - | - | - | - |

PF - Periodic Event Flag

This bit is set to a 1 every t_{PI} time, where t_{PI} is the time period selected by the settings of RS0–RS3 in register A. Reading register C clears this bit.

INTF - Interrupt Request Flag

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|---|---|---|---|---|---|---|
| INTF | - | - | - | - | - | - | - |

This flag is set to a 1 when any of the following is true:

AIE = 1 and AF = 1

PIE = 1 and PF = 1

UIE = 1 and UF = 1

Reading register C clears this bit.

Register D

| Register D Bits | | | | | | | | | |
|-----------------|---|---|---|---|---|---|---|--|--|
| 7 6 5 4 3 2 1 0 | | | | | | | | | |
| VRT | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | |

Register D is the read-only data integrity status register

Bits 0-6 - Unused Bits

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| - | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

These bits are always set to 0.

VRT - Valid RAM and Time

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| VRT | _ | - | _ | - | _ | - | _ |

1 =Valid backup energy source

0 = Backup energy source is depleted

When the backup energy source is depleted (VRT = 0), data integrity of the RTC and storage registers is not guaranteed.

bq4285

Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit | Conditions |
|--------------------|---|-------------|----------------------|------------------------|
| $V_{\rm CC}$ | DC voltage applied on $V_{\rm CC}$ relative to $V_{\rm SS}$ | -0.3 to 7.0 | V | |
| V_{T} | DC voltage applied on any pin excluding $V_{\rm CC}$ relative to $V_{\rm SS}$ | -0.3 to 7.0 | V | $V_T \le V_{CC} + 0.3$ |
| T _{OPR} | Operating temperature | 0 to +70 | $^{\circ}\mathrm{C}$ | Commercial |
| T_{STG} | Storage temperature | -55 to +125 | $^{\circ}\mathrm{C}$ | |
| T _{BIAS} | Temperature under bias | -40 to +85 | $^{\circ}\mathrm{C}$ | |
| TSOLDER | Soldering temperature | 260 | $^{\circ}\mathrm{C}$ | For 10 seconds |

Note:

Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

Recommended DC Operating Conditions (TA = TOPR)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit |
|-------------------|---------------------|---------|---------|--------------------|------|
| $V_{\rm CC}$ | Supply voltage | 4.5 | 5.0 | 5.5 | V |
| $V_{\rm SS}$ | Supply voltage | 0 | 0 | 0 | V |
| $V_{\rm IL}$ | Input low voltage | -0.3 | - | 0.8 | V |
| V_{IH} | Input high voltage | 2.2 | - | $V_{\rm CC}$ + 0.3 | V |
| V_{BC} | Backup cell voltage | 2.5 | - | 4.0 | V |

Note:

Typical values indicate operation at T_A = 25°C.

DC Electrical Characteristics (TA = TOPR, VCC = 5V \pm 10%)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit | Conditions/Notes |
|------------------------------|----------------------------|------------------------|----------|---------|------|---|
| I_{LI} | Input leakage current | - | - | ± 1 | μΑ | $V_{\rm IN}$ = $V_{\rm SS}$ to $V_{\rm CC}$ |
| I_{LO} | Output leakage current | - | - | ± 1 | μΑ | $\begin{array}{c} AD_0AD_7, \overline{INT}, \text{and} \\ SQW \text{in high impedance}, \\ V_{OUT} = V_{SS} \text{to} V_{CC} \end{array}$ |
| V _{OH} | Output high voltage | 2.4 | - | - | V | I _{OH} = -2.0 mA |
| V_{OL} | Output low voltage | - | - | 0.4 | V | $I_{\rm OL}$ = 4.0 mA |
| I_{CC} | Operating supply current | - | 7 | 15 | mA | $\begin{aligned} &\text{Min. cycle, duty = } 100\%, \\ &I_{OH} = 0\text{mA}, I_{OL} = 0\text{mA} \end{aligned}$ |
| V_{SO} | Supply switch-over voltage | - | V_{BC} | - | V | |
| I_{CCB} | Battery operation current | - | 0.3 | 0.5 | μΑ | $V_{BC}=3V,T_{A}=25^{\circ}C,n_{OUT}$ load on V_{OUT} or \overline{CE}_{OUT} |
| $ m V_{PFD}$ | Power-fail-detect voltage | 4.0 | 4.17 | 4.35 | V | |
| V _{OUT1} | V _{OUT} voltage | V _{CC} - 0.3V | - | - | V | $I_{OUT} = 100$ mA, $V_{CC} > V_{BC}$ |
| V _{OUT2} | V _{OUT} voltage | V _{BC} - 0.3V | | | | $I_{OUT} = 100 \mu A, V_{CC} < V_{BC}$ |
| | | | | | | |
| $\overline{\mathrm{I_{CE}}}$ | Chip enable input current | - | - | 100 | μΑ | Internal 50K pull-up |

Note: Typical values indicate operation at $T_A = 25^{\circ}C, V_{CC} = 5V$ or $V_{BC} = 3V$.

Crystal Specifications (DT-26 or Equivalent)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit |
|--------------------------------|------------------------------|---------|---------|---------|--------|
| fo | Oscillation frequency | - | 32.768 | - | kHz |
| C_{L} | Load capacitance | - | 6 | - | pF |
| T_{P} | Temperature turnover point | 20 | 25 | 30 | °C |
| k | Parabolic curvature constant | - | - | -0.042 | ppm/°C |
| Q | Quality factor | 40,000 | 70,000 | - | |
| R ₁ | Series resistance | - | - | 45 | ΚΩ |
| C ₀ | Shunt capacitance | - | 1.1 | 1.8 | pF |
| C ₀ /C ₁ | Capacitance ratio | - | 430 | 600 | |
| $\mathrm{D_{L}}$ | Drive level | - | - | 1 | μW |
| Δf/f _O | Aging (first year at 25°C) | - | 1 | - | ppm |

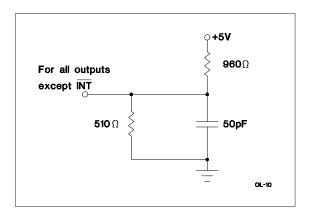
Capacitance (TA = 25°C, F = 1MHz, VCC = 5.0V)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit | Conditions |
|------------------|--------------------------|---------|---------|---------|------|-------------------|
| C _{I/O} | Input/output capacitance | - | - | 7 | pF | $V_{OUT} = 0V$ |
| C_{IN} | Input capacitance | - | - | 5 | pF | $V_{\rm IN} = 0V$ |

Note: This parameter is sampled and not 100% tested.

AC Test Conditions

| Parameter | Test Conditions | | | |
|--|------------------------------------|--|--|--|
| Input pulse levels | 0 to 3.0 V | | | |
| Input rise and fall times | 5 ns | | | |
| Input and output timing reference levels | 1.5 V (unless otherwise specified) | | | |
| Output load (including scope and jig) | See Figures 5 and 6 | | | |



1.15K Ω

1.15K Ω

1.10pF

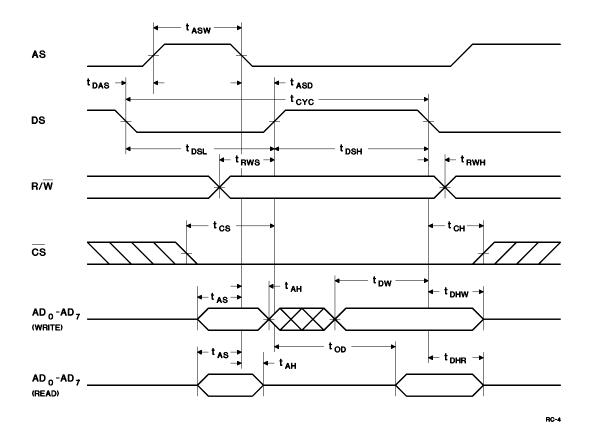
Figure 5. Output Load A

Figure 6. Output Load B

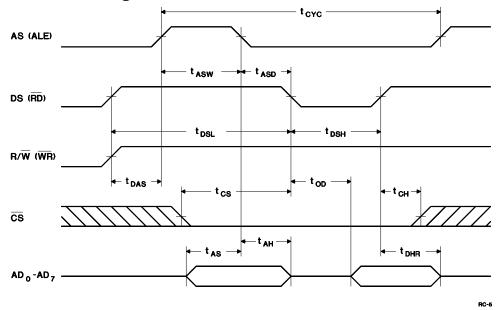
Read/Write Timing (TA = TOPR, VCC = 5V \pm 10%)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit | Notes |
|--------------------|--|---------|---------|---------|------|-------------|
| t_{CYC} | Cycle time | 160 | - | - | ns | |
| ${ m t_{DSL}}$ | \overline{DS} low or $\overline{RD}/\overline{WR}$ high time | 80 | - | - | ns | |
| $t_{ m DSH}$ | DS high or $\overline{RD}/\overline{WR}$ low time | 55 | - | - | ns | |
| t_{RWH} | R/W hold time | 0 | - | - | ns | |
| $t_{ m RWS}$ | R/W setup time | 10 | - | - | ns | |
| t_{CS} | Chip select setup time | 5 | - | - | ns | |
| t_{CH} | Chip select hold time | 0 | - | - | ns | |
| ${ m t_{DHR}}$ | Read data hold time | 0 | - | 25 | ns | |
| $t_{ m DHW}$ | Write data hold time | 0 | - | - | ns | |
| t_{AS} | Address setup time | 20 | - | - | ns | |
| t_{AH} | Address hold time | 5 | - | - | ns | |
| t_{DAS} | Delay time, DS to AS rise | 10 | - | - | ns | |
| t_{ASW} | Pulse width, AS high | 30 | - | - | ns | |
| $t_{ m ASD}$ | $\frac{\text{Delay time, AS to DS rise}}{(\overline{\text{RD/WR}}\text{ fall})}$ | 35 | - | - | ns | |
| $t_{\rm OD}$ | Output data delay time from DS rise (RD fall) | - | - | 50 | ns | |
| t_{DW} | Write data setup time | 30 | - | - | ns | |
| $t_{ m BUC}$ | Delay time before update | - | 244 | - | μs | |
| $t_{ m PI}$ | Periodic interrupt time interval | - | - | - | - | See Table 3 |
| ${ m t_{UC}}$ | Time of update cycle | - | 1 | - | μs | |

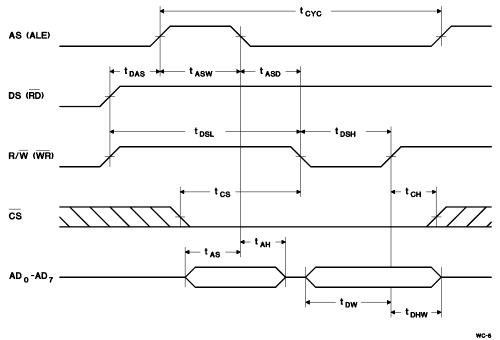
Motorola Bus Read/Write Timing (PLCC Package Only) Note: OBSOLETE



Intel Bus Read Timing



Intel Bus Write Timing

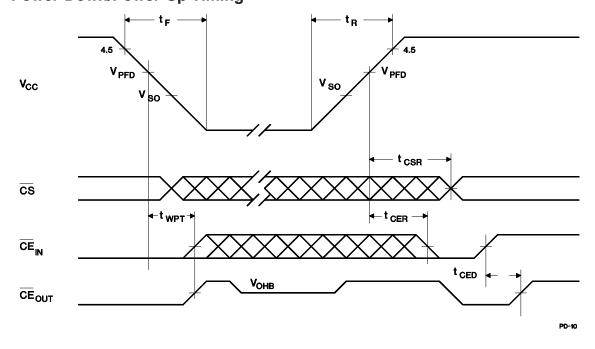


Power-Down/Power-Up Timing (TA = TOPR)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit | Conditions |
|--------------------|---|--------------------|---------|--------------------|------|--|
| $t_{ m F}$ | $V_{\rm CC}$ slew from 4.5V to 0V | 300 | - | - | μs | |
| $t_{ m R}$ | V _{CC} slew from 0V to 4.5V | 100 | - | - | μs | |
| $t_{\rm CSR}$ | $\overline{\mbox{CS}}$ at $\mbox{V}_{\mbox{\scriptsize IH}}$ after power-up | 20 | ı | 200 | ms | $\begin{array}{c} Internal\ write-protection\\ period\ after\ V_{CC}\ passes\ V_{PFD}\\ on\ power-up. \end{array}$ |
| t_{WPT} | Write-protect time for external RAM | 10 | 6 | 30 | μs | Delay after V _{CC} slews down past V _{PFD} before SRAM is write-protected. |
| $t_{\rm CER}$ | Chip enable recovery time | t_{CSR} | - | t_{CSR} | ms | Time during which external SRAM is write-protected after $V_{\rm CC}$ passes $V_{\rm PFD}$ on power-up. |
| $t_{\rm CED}$ | Chip enable propagation delay to external SRAM | - | 7 | 10 | ns | |

Caution: Negative undershoots below the absolute maximum rating of -0.3V in battery-backup mode may affect data integrity.

Power-Down/Power-Up Timing

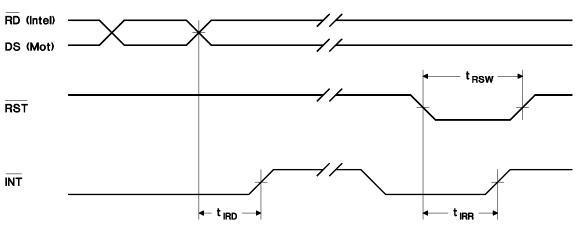


INT-1

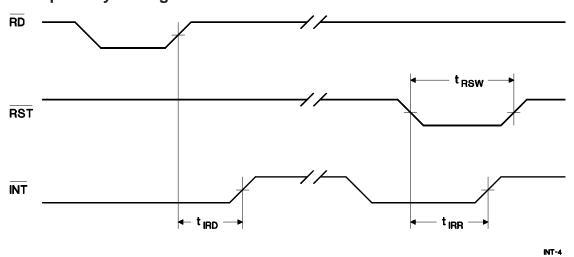
Interrupt Delay Timing (TA = TOPR)

| Symbol | Parameter | Minimum | Typical | Maximum | Unit |
|---------------|--|---------|---------|---------|------|
| $t_{ m RSW}$ | Reset pulse width | 5 | - | - | μs |
| $t_{\rm IRR}$ | $\overline{	ext{INT}}$ release from $\overline{	ext{RST}}$ | - | - | 2 | μs |
| $t_{ m IRD}$ | $\overline{\mathrm{INT}}$ release from DS $(\overline{\mathrm{RD}})$ | - | - | 2 | μs |

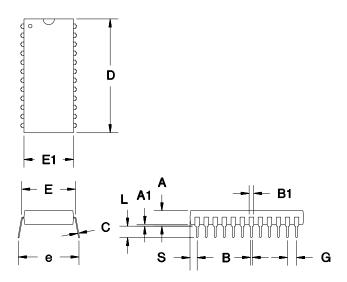
Interrupt Delay Timing (PLCC Package Only) Note: Package OBSOLETE



Interrupt Delay Timing



24-Pin DIP (P)

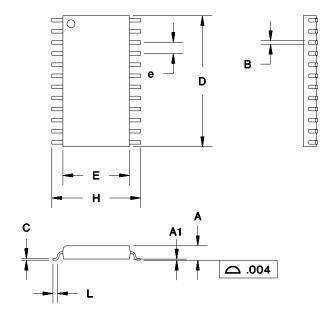


24-Pin DIP (P)

| Dimension | Minimum | Maximum |
|-----------|---------|---------|
| A | 0.160 | 0.190 |
| A1 | 0.015 | 0.040 |
| В | 0.015 | 0.022 |
| B1 | 0.045 | 0.065 |
| С | 0.008 | 0.013 |
| D | 1.240 | 1.280 |
| E | 0.600 | 0.625 |
| E1 | 0.530 | 0.570 |
| e | 0.600 | 0.670 |
| G | 0.090 | 0.110 |
| L | 0.115 | 0.150 |
| S | 0.070 | 0.090 |

All dimensions are in inches.

24-Pin SOIC (S)



24-Pin SOIC (S)

| | ` ' | |
|-----------|---------|---------|
| Dimension | Minimum | Maximum |
| A | 0.095 | 0.105 |
| A1 | 0.004 | 0.012 |
| В | 0.013 | 0.020 |
| C | 0.008 | 0.013 |
| D | 0.600 | 0.615 |
| E | 0.290 | 0.305 |
| e | 0.045 | 0.055 |
| Н | 0.395 | 0.415 |
| L | 0.020 | 0.040 |

All dimensions are in inches.

bq4285

Data Sheet Revision History

| Change No. | Page No. | Description | Natur of Change |
|---------------|--------------------------------|--|---|
| 1 | 3 | Address strobe input | Clarification |
| 1 | 12 | Backup cell voltage V _{BC} | Was 2.0 min; is 2.5 min |
| 1 | 13 | Power-fail detect voltage V _{PFD} | Was 4.1 min, 4.25 max; is 4.0 min, 4.35 max |
| 1 | 13 | Chip enable input current | Additional specifiction |
| 2 | 3, 13 | Crystal type Daiwas DT-26 (not DT-26S) | Clarification |
| 3 | 1, 20, 22 | Package option change | PLCC last time buy |
| 4 | 1, 2, 3, 13, 16, 19, 21, 23 | Package option removal | PLCC Last Time Buy Complete |

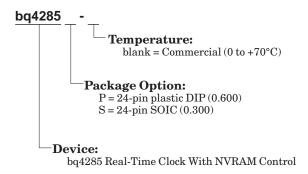
Note: Change 1 = Nov. 1992 B changes from June 1991 A.

Change 2 = Nov. 1993 C changes from Nov. 1992 B

Change 3 = Jan. 1999 D changes from Nov. 1993 C

Change 4 = May 2004 (SLUS002A) changes from Jan. 1999 D

Ordering Information







11-Apr-2013

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | | Lead/Ball Finish | | Op Temp (°C) | Top-Side Markings | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|-------------------|---------|
| | (1) | | Drawing | | Qty | (2) | | (3) | | (4) | |
| BQ4285P-SB2 | ACTIVE | PDIP | N | 24 | 15 | Pb-Free (RoHS) | A42 SN | N / A for Pkg Type | 0 to 70 | 4285P -SB2 | Samples |
| BQ4285S-SB2 | ACTIVE | SOIC | DW | 24 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 4285S -SB2 | Samples |
| BQ4285S-SB2G4 | ACTIVE | SOIC | DW | 24 | 25 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 4285S -SB2 | Samples |
| BQ4285S-SB2TR | ACTIVE | SOIC | DW | 24 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 4285S -SB2 | Samples |
| BQ4285S-SB2TRG4 | ACTIVE | SOIC | DW | 24 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 4285S -SB2 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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⁽³⁾ MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.



PACKAGE OPTION ADDENDUM

11-Apr-2013

| In no event shall TI's liability | arisino | out of such information | n exceed the total pu | urchase price o | of the TI part(s | at issue in this | document sold by | TI to Customer on an annual basis. |
|----------------------------------|---------|-------------------------|-----------------------|-----------------|------------------|------------------|------------------|------------------------------------|
| | | | | | | | | |

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Dec-2012

TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ4285S-SB2TR | SOIC | DW | 24 | 2000 | 330.0 | 24.4 | 10.75 | 15.7 | 2.7 | 12.0 | 24.0 | Q1 |

www.ti.com 20-Dec-2012

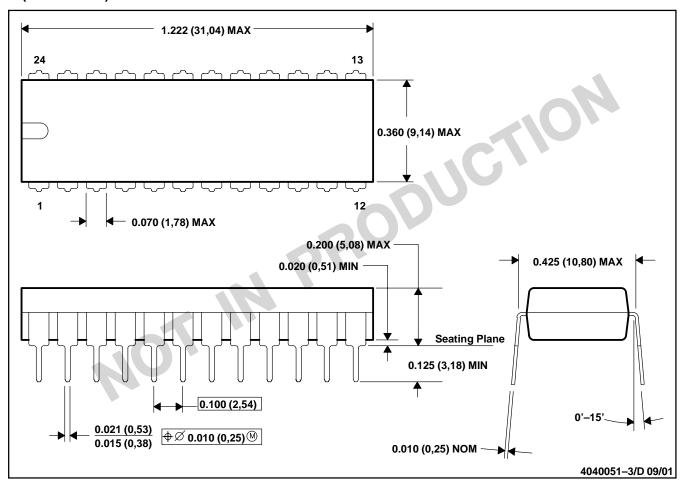


*All dimensions are nominal

| Device Package Type | | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|---------------------|------|-----------------|------|------|-------------|------------|-------------|--|
| BQ4285S-SB2TR | SOIC | DW | 24 | 2000 | 367.0 | 367.0 | 45.0 | |

N (R-PDIP-T24)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-010

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



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